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**The Design and Analysis of CMOS Double-
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PUBLICATION LIST

(A) JOURNAL PAPERS

- [1] **Chung-Yun Chou**, and Chung-Yu Wu, “The Design of Wideband and Low-Power CMOS Active Polyphase Filter and Its Application in RF Double-Quadrature Receivers,” accepted by *IEEE Transactions on Circuits and Systems I*.
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(B) CONFERENCE PAPERS

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